

# Full - Bridge MOSFET Power Module

OUT1 OUT2

VBUS

Q3

Q4

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G3

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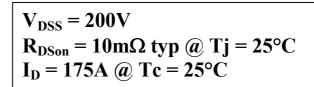
S3

G4

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S4





- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

### Features

- Power MOS 7<sup>®</sup> FREDFETs
  - Low R<sub>DSon</sub>
    - Low input and Miller capacitance
    - Low gate charge
    - Fast intrinsic reverse diode
    - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

### Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

# Absolute maximum ratings

G1 C

 $\bigcirc$ 

S1

G2

С

S2

Q2

Symbol	Parameter		Max ratings	Unit	
$V_{DSS}$	Drain - Source Breakdown Voltage		200	V	
$I_D$	Continuous Drain Current	$T_c = 25^{\circ}C$	175		
	Continuous Drain Current	$T_c = 80^{\circ}C$	131	А	
I <sub>DM</sub>	Pulsed Drain current		700		
V <sub>GS</sub>	Gate - Source Voltage		±30	V	
R <sub>DSon</sub>	Drain - Source ON Resistance		12	mΩ	
PD	Maximum Power Dissipation	$T_c = 25^{\circ}C$	694	W	
I <sub>AR</sub>	Avalanche current (repetitive and non repetitive)		89	А	
EAR	Repetitive Avalanche Energy		50	mJ	
E <sub>AS</sub>	Single Pulse Avalanche Energy		2500	IIIJ	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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www.microsemi.com

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# All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

# **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 200V$	$T_j = 25^{\circ}C$			200	μA
		$V_{GS} = 0V, V_{DS} = 160V$	$T_{j} = 125^{\circ}C$			1000	
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 87.5A$			10	12	mΩ
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5mA$		3		5	V
I <sub>GSS</sub>	Gate – Source Leakage Current	$V_{GS} = \pm 30 V, V_{DS} = 0$	V			±150	nA

# **Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C <sub>iss</sub>	Input Capacitance	$V_{GS} = 0V$		13.7		
Coss	Output Capacitance	$V_{\rm DS} = 25 V$		4.36		nF
C <sub>rss</sub>	Reverse Transfer Capacitance	f = 1 MHz		0.19		
Qg	Total gate Charge	$V_{GS} = 10V$		224		nC
$Q_{gs}$	Gate – Source Charge	$V_{Bus} = 100V$		86		
$Q_{gd}$	Gate – Drain Charge	$I_D = 150A$		94		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive switching @ 125°C		28		ns
Tr	Rise Time	$V_{GS} = 15V$ $V_{Bus} = 133V$ $I_D = 150A$ $R_G = 2.5\Omega$		56		
T <sub>d(off)</sub>	Turn-off Delay Time			81		
$T_{\rm f}$	Fall Time			99		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V$ , $V_{Bus} = 133V$ $I_D = 150A$ , $R_G = 2.5\Omega$		926		т
E <sub>off</sub>	Turn-off Switching Energy			910		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C $V_{GS} = 15V, V_{Bus} = 133V$ $I_D = 150A, R_G = 2.5\Omega$		1216		т
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy			1062		μJ

# Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Is	Continuous Source current		$Tc = 25^{\circ}C$			175	А
IS	(Body diode)	Т	$Tc = 80^{\circ}C$			131	Л
$V_{SD}$	Diode Forward Voltage	$V_{GS} = 0V, I_S = -150A$				1.3	V
dv/dt	Peak Diode Recovery <b>1</b>					8	V/ns
t <sub>rr</sub>	Reverse Recovery Time	1. 1.50 4	$T_j = 25^{\circ}C$			220	ns
	Reverse Receivery Time	$I_{\rm S} = -150 \text{A}$ $V_{\rm R} = 133 \text{V}$	$T_{j} = 125^{\circ}C$			420	115
Q <sub>rr</sub>	Reverse Recovery Charge	$di_s/dt = 200A/\mu s$	$T_j = 25^{\circ}C$		2.14		μC
	Reverse Recovery Charge		$T_{i} = 125^{\circ}C$		5.8		μ

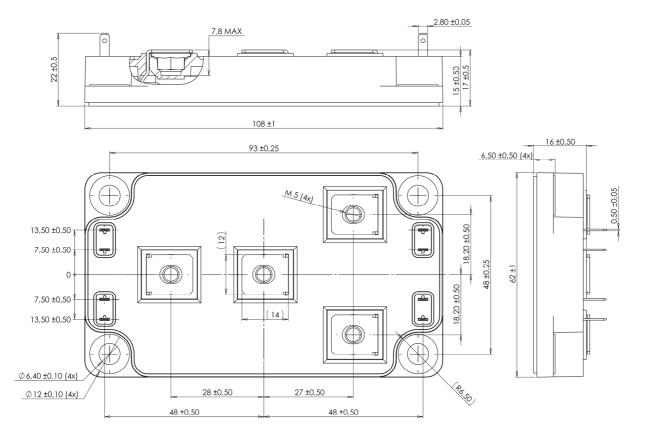
• dv/dt numbers reflect the limitations of the circuit rather than the device itself.  $I_S \leq -150A$  di/dt  $\leq 700A/\mu s$   $V_R \leq V_{DSS}$   $T_j \leq 150^{\circ}C$ 



# Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R <sub>thJC</sub>	Junction to Case Thermal Resistance					0.18	°C/W
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
TJ	Operating junction temperature range			-40		150	°C
T <sub>STG</sub>	Storage Temperature Range			-40		125	
T <sub>C</sub>	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	19.111
Wt	Package Weight					300	g

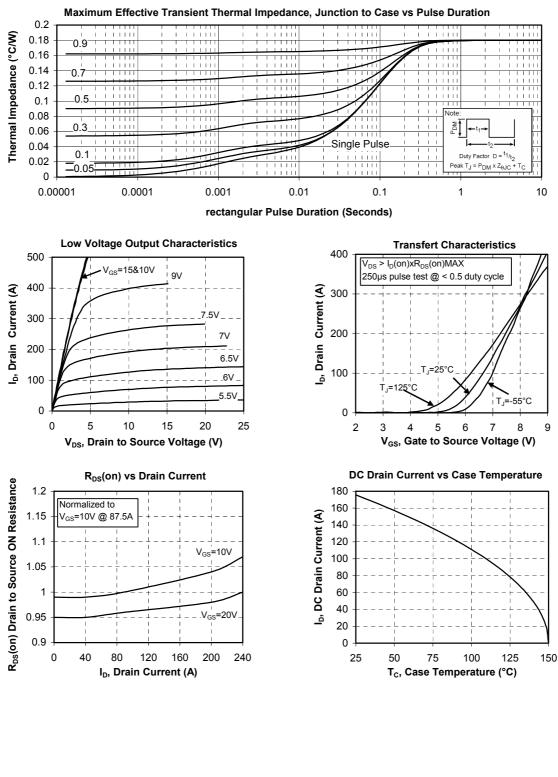
# SP6 Package outline (dimensions in mm)



See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

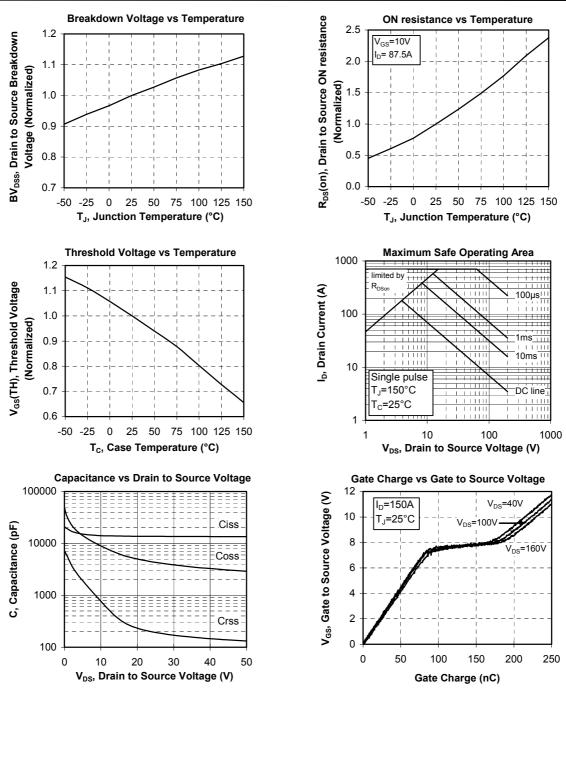


## **Typical Performance Curve**

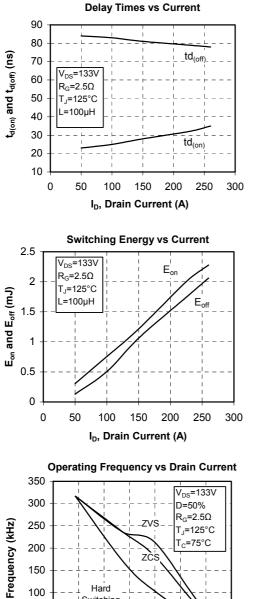


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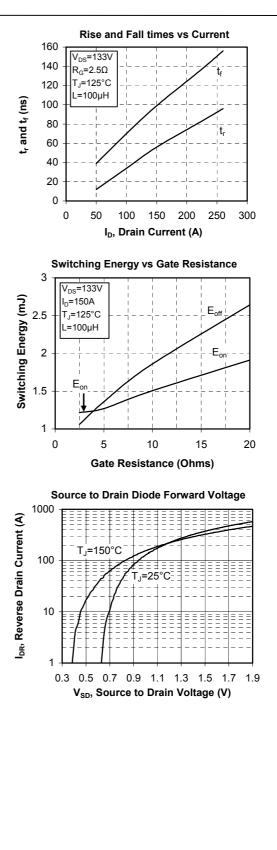






Switching 50 0 20 40 60 80 100 120 140 160 I<sub>D</sub>, Drain Current (A)

# **APTM20HM10FG**





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